

Xi Zhang

List of Publications by Year in descending order

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5
papers

72
citations

1937685
4
h-index

2272923
4
g-index

5
all docs

5
docs citations

5
times ranked

86
citing authors

#	ARTICLE	IF	CITATIONS
1	Tuning of Schottky barrier height using oxygen-inserted (OI) layers and fluorine implantation. AIP Advances, 2020, 10, 065310.	1.3	0
2	Effects of oxygen-inserted layers on diffusion of boron, phosphorus, and arsenic in silicon for ultra-shallow junction formation. Journal of Applied Physics, 2018, 123, .	2.5	6
3	Effects of oxygen-inserted layers and oxide capping layer on dopant activation for the formation of ultrashallow p-n junctions in silicon. Journal of Vacuum Science and Technology B: Nanotechnology and Microelectronics, 2018, 36, 061211.	1.2	4
4	Comparison of SOI Versus Bulk FinFET Technologies for 6T-SRAM Voltage Scaling at the 7-/8-nm Node. IEEE Transactions on Electron Devices, 2017, 64, 329-332.	3.0	32
5	Analysis of 7/8-nm Bulk-Si FinFET Technologies for 6T-SRAM Scaling. IEEE Transactions on Electron Devices, 2016, 63, 1502-1507.	3.0	30